



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

August 28, 2025

IGI Report Number

LG724559454

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

SQUARE EMERALD CUT

Measurements

5.72 X 5.64 X 3.71 MM

GRADING RESULTS

Carat Weight

1.06 CARAT

Color Grade

D

Clarity Grade

VS 1

ADDITIONAL GRADING INFORMATION

Polish

EXCELLENT

Symmetry

EXCELLENT

Fluorescence

NONE

Inscription(s)

IGI LG724559454

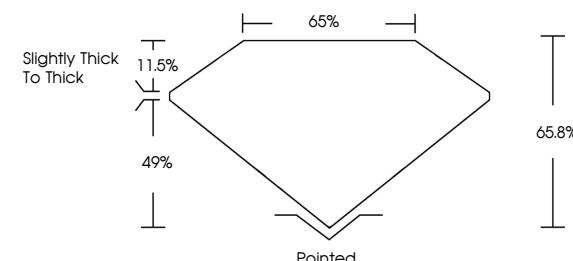
Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.

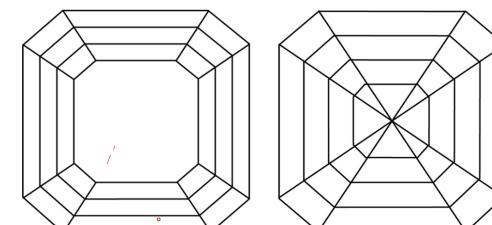
Type II

LG724559454
Report verification at igi.org

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

www.igi.org

© IGI 2020, International Gemological Institute

August 28, 2025

IGI Report No LG724559454

SQUARE EMERALD CUT

5.72 X 5.64 X 3.71 MM

1.06 CARAT

D

VS 1

65.8%

65%

Slightly Thick to Thick

Pointed

EXCELLENT

EXCELLENT

NONE

IGI LG724559454

Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.

Type II

LABORATORY GROWN DIAMOND REPORT



August 28, 2025

IGI Report Number

LG724559454

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **SQUARE EMERALD CUT**

Measurements **5.72 X 5.64 X 3.71 MM**

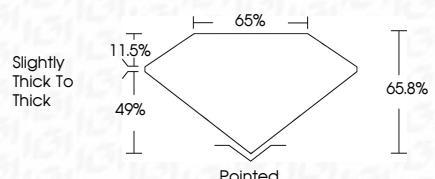
GRADING RESULTS

Carat Weight **1.06 CARAT**

D

Color Grade **VS 1**

Clarity Grade **VS 1**



ADDITIONAL GRADING INFORMATION

Polish **EXCELLENT**

Symmetry **EXCELLENT**

Fluorescence **NONE**

Inscription(s) **IGI LG724559454**

Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.

Type II



IGI



FD - 10 20

Comments: As Grown - No indication of post-growth treatment.

This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.

Type II